Diode Semiconductor Device - Page 1 of 1



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**Inclosure Material:** 

Metal

**Overall Length:** 

0.255 millimeters

Terminal Length:

0.180 millimeters

# **Overall Height:**

0.095 millimeters

### **Overall Width:**

0.155 millimeters

### **End Application:**

Kok-22ae/ifscm12954

### **Mounting Facility Quantity:**

2

### Mounting Method:

Bracket

### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

9.0 reverse breakdown voltage, dc and 50.0 working peak reverse voltage, peak total value, gate terminal open-circuited

## **Current Rating Per Characteristic:**

44.00 amperes zero-gate-voltage source current blank

# **Power Rating Per Characteristic:**

600.0 watts small-signal output power, common-base preset

## Maximum Operating Tempurature Per Measurement Point:

-65.0 degrees celsius case and 175.0 degrees celsius case

## **Terminal Type And Quantity:**

2 case

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0